## Comparison of the power losses in 1700V Si IGBT and SiC MOSFET modules including reverse conduction [Electronic resource]

**Rabkowski, Jacek**; Platek, Tadeusz EPE'15 ECCE Europe: 8-10 September 2015, Geneva, Switzerland: 17th European Conference on Power Electronics and Applications 2015 / [10] p.: ill. [USB] http://dx.doi.org/10.1109/EPE.2015.7309444

## Implementation possibilities of SMD capacitors for high power applications

**Zakis, Janis**; **Vinnikov, Dmitri** Riga Technical University 53rd International Scientific Conference dedicated to the 150th anniversary and the 1st Congress of World Engineers and Riga Polytechnical Institute/RTU Alumni: 11-12 October 2012, Riga, Latvija: [abstracts] 2012 / p. 128: ill <a href="https://intapi.sciendo.com/pdf/10.2478/v10314-012-0003-2">https://intapi.sciendo.com/pdf/10.2478/v10314-012-0003-2</a>